

S9014 TRANSISTOR (NPN)

FEATURES

- High total power dissipation. ($P_c=0.45W$)
- High hFE and good linearity
- Complementary to S9015

TO-92



MAXIMUM RATINGS ($T_A=25^\circ C$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------|-------------------------------|---------|-------|
| V_{CBO} | Collector-Base Voltage | 50 | V |
| V_{CEO} | Collector-Emitter Voltage | 45 | V |
| V_{EBO} | Emitter-Base Voltage | 5 | V |
| I_c | Collector Current -Continuous | 0.1 | A |
| P_c | Collector Power Dissipation | 0.45 | W |
| T_J | Junction Temperature | 150 | °C |
| T_{stg} | Storage Temperature | -55-150 | °C |

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ C$ unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|---------------|-------------------------------------|-----|-----|------|---------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_c=100\mu A, I_E=0$ | 50 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_c=1mA, I_B=0$ | 45 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=100\mu A, I_C=0$ | 5 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=50V, I_E=0$ | | | 0.1 | μA |
| Collector cut-off current | I_{CEO} | $V_{CE}=35V, I_B=0$ | | | 0.1 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}= 5V, I_C=0$ | | | 0.1 | μA |
| DC current gain | h_{FE} | $V_{CE}=5V, I_c= 1mA$ | 60 | | 1000 | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_c=100mA, I_B= 5mA$ | | | 0.3 | V |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | $I_c=100mA, I_B= 5mA$ | | | 1 | V |
| Transition frequency | f_T | $V_{CE}=5V, I_c= 10mA$ $f=30MHz$ | 150 | | | MHz |

CLASSIFICATION OF $h_{FE(1)}$

| Rank | A | B | C | D |
|-------|--------|---------|---------|---------|
| Range | 60-150 | 200-300 | 250-300 | 300-400 |